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PRELIMINARY AMENDMENT

Serial Number: Unassigned Filing Date: Herewith

Title: ELECTRICALLY TUNED INTEGRATED AMPLIFIER FOR WIRELESS COMMUNICATIONS

Assignee: Intel Corporation

IN THE CLAIMS

Please amend the claims as follows:

Claims 1-24. (Canceled)

25. (Currently Amended) A multi-band radio frequency (RF) receiver system comprising:
a multi-band low noise amplifier (LNA) to amplify a receive signal, said multi-band LNA
including a resonant circuit having a plurality of circuit elements, said plurality of circuit
elements including a voltage variable capacitance, said multi-band LNA having a plurality of
operational frequency bands, wherein a present operational frequency band of said multi-band
LNA depends upon a present value of said voltage variable capacitance;

a receiver coupled to an output of said multi-band low noise amplifier to process an amplified version of said receive signal; and

a controller coupled to said multi-band LNA to change a value of said voltage variable capacitance when a change in the <u>present</u> operational frequency <u>range</u> <u>band</u> of said multi-band LNA is desired.

- 26. (Original) The multi-band RF receiver system claimed in claim 25, wherein: said multi-band LNA includes a voltage adjustment unit to vary a bias voltage on said voltage variable capacitance based on a control signal generated by said controller.
- 27. (Original) The multi-band RF receiver system claimed in claim 26, wherein: said voltage adjustment unit includes a transistor having two output terminals that are coupled between a supply terminal and said voltage variable capacitance.
- 28. (Original) The multi-band RF receiver system claimed in claim 25, wherein: said multi-band LNA includes a cascode core having multiple transistors, wherein said voltage variable capacitance of said resonant circuit is a parasitic capacitance of one of said multiple transistors.
- 29. (Original) The multi-band RF receiver system claimed in claim 25, wherein:

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said multi-band LNA, said receiver, and said controller are integrated onto a common semiconductor chip.

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- 30. (Original) The multi-band RF receiver system claimed in claim 25, comprising:
- a look up table (LUT) to store a plurality of control values that each correspond to a particular operational frequency band of said multi-band LNA.
- 31. (Original) An electronic system comprising:

an antenna;

- a cascode core including an input transistor to receive a signal from the antenna and a first transistor having a parasitic capacitance that varies with a bias voltage applied thereto; and a tuning transistor to vary the bias voltage on the first transistor.
- 32. (Original) The electronic system of claim 31 further comprising a resonant circuit coupled between the tuning transistor and the cascode core, said parasitic capacitance of said first transistor affecting a center frequency of said resonant circuit.
- 33. (Original) The electronic system of claim 31 further comprising a controller to influence the bias voltage on the first transistor.
- 34. (Original) The electronic system of claim 33 further comprising a lookup table coupled to the controller, the lookup table to store values that influence the bias voltage on the first transistor.
- 35. (Original) An electronic system comprising:

an amplifier including a cascode core having a transistor with a parasitic capacitance that varies with a bias voltage, and including a control transistor to vary the bias voltage;

- a receiver to receive a first signal from the amplifier; and
- a signal processing unit to receive a second signal from the receiver.
- 36. (Original) The electronic system of claim 35 further comprising a lookup table to influence operation of the control transistor.

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37. (Original) The electronic system of claim 36 further comprising a controller coupled between the lookup table and the control transistor.

- 38. (Original) The multi-band RF receiver system claimed in claim 25, wherein: said multi-band LNA is a differential amplifier.
- 39. (Original) The multi-band RF receiver system claimed in claim 25, wherein: said resonant circuit further comprises an inductor and a capacitor coupled in parallel.
- 40. (Original) The multi-band RF receiver system claimed in claim 25, further comprising: a receive antenna coupled to said multi-band LNA to receive said receive signal from an exterior environment and to transfer said receive signal to said multi-band LNA; and a signal processing unit coupled to said receiver to receive a baseband signal to process said baseband signal.
- 41. (Original) The electronic system of claim 32, wherein: said resonant circuit further comprises an inductor and a capacitor coupled in parallel.
- 42. (Original) The electronic system of claim 33, wherein:
 said tuning transistor comprises two output terminals coupled between a supply terminal
 and said first transistor, said tuning transistor further comprising a control terminal coupled to
 said controller to receive a control signal.
- 43. (Original) The electronic system of claim 31, wherein:
 said cascode core, said tuning transistor, and a resonant circuit coupled between said
 cascode core and said tuning transistor comprise a low noise amplifier (LNA) to amplify said

further comprising:

signal from said antenna to generate an amplified signal; and

a receiver coupled to the LNA to receive said amplified signal from said LNA and to generate a baseband signal from said amplified signal; and

a signal processing unit coupled to said receiver to receive said baseband signal to process said baseband signal.

- 44. (Original) The electronic system of claim 43, wherein: said LNA is a differential amplifier.
- 45. (Original) The electronic system of claim 43, wherein: said LNA, said receiver, a controller coupled to the LNA, and a look up table (LUT) coupled to the controller are integrated on a common semiconductor chip.
- 46. (Original) The electronic system of claim 37, wherein: said amplifier, said receiver, said controller, and said lookup table are integrated on a common semiconductor chip.
- 47. (Original) The electronic system of claim 35, wherein:
 said amplifier further comprises a resonant circuit coupled between said cascode core and said control transistor, said resonant circuit comprising an inductor and a capacitor coupled in parallel.
- 48. (Original) The electronic system of claim 47, wherein: said amplifier is a differential amplifier.
- 49. (Original) The electronic system of claim 35, further comprising:
 a receive antenna coupled to said amplifier to receive an RF signal from an exterior
 environment and to transfer said RF signal to said amplifier.
- 50. (Original) An electronic system comprising:

 a dipole antenna to receive an RF signal from an exterior environment;

 a low noise amplifier (LNA) coupled to said dipole antenna to receive said RF signal to

 amplify said RF signal with a resonant circuit to generate an amplified signal, said resonant

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circuit comprising a parasitic capacitance that varies with a bias voltage on said parasitic capacitance to adjust a resonant frequency of said resonant circuit;

- a controller coupled to said LNA to vary said bias voltage on said parasitic capacitance;
- a look up table coupled to said controller to provide control values to said controller;
- a receiver coupled to said LNA to receive said amplified signal from said LNA and to generate a baseband signal from said amplified signal; and
- a signal processing unit coupled to said receiver to receive said baseband signal to process said baseband signal.
- 51. (Original) The electronic system of claim 50, wherein: said LNA is a differential amplifier.
- 52. (Original) The electronic system of claim 50, wherein:

said resonant circuit comprises an inductor and a capacitor coupled in parallel between a cascode core and a control transistor, said cascode core comprising a transistor comprising said parasitic capacitance, said control transistor comprising a control terminal coupled to said controller to receive a control signal based on said control values from said look up table, said control transistor further comprising two terminals coupled between a supply terminal and said parasitic capacitance.

53. (Original) A method for operating an electronic system comprising: receiving an RF signal at an antenna;

amplifying said RF signal in an amplifier coupled to said antenna with a resonant circuit in said amplifier to generate an amplified signal;

adjusting a bias voltage on a parasitic capacitance in said resonant circuit with a controller coupled to said amplifier to vary said parasitic capacitance to change a resonant frequency of said resonant circuit;

providing control values to said controller from a look up table coupled to said controller, said controller to adjust said bias voltage according to said control values;

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generating a baseband signal from said amplified signal in a receiver coupled to said amplifier; and

processing said baseband signal in a signal processing unit coupled to said receiver.

54. (Original) The method of claim 53, wherein:

amplifying said RF signal further comprises amplifying said RF signal in a differential amplifier coupled to said antenna with a resonant circuit in said differential amplifier to generate said amplified signal.

55. (Original) The method of claim 53, wherein:

adjusting a bias voltage further comprises adjusting said bias voltage on a transistor comprising said parasitic capacitance in a cascode core in said resonant circuit by controlling a control transistor with a control signal from said controller, said control transistor further comprising two terminals coupled between a supply terminal and said parasitic capacitance; and

amplifying said RF signal further comprises filtering said RF signal to pass signal components within a desired operational frequency range with said resonant circuit, said resonant circuit comprising an inductor and a capacitor coupled in parallel between said cascode core and said control transistor to generate said amplified signal.

56. (Original) The method of claim 53, wherein adjusting a bias voltage further comprises: monitoring said resonant frequency of said resonant circuit; and

adjusting said bias voltage on a transistor comprising said parasitic capacitance in a cascode core in the resonant circuit by controlling a control transistor with a control signal from said controller until said resonant frequency is within a predetermined frequency range, said control transistor further comprising two terminals coupled between a supply terminal and said parasitic capacitance.

57. (Original) The method of claim 56, further comprising:

blocking power supply noise from said supply terminal during operation of said amplifier with said control transistor.

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58. (Original) The method of claim 53, wherein adjusting a bias voltage further comprises: providing a control value to said controller from said look up table to change a frequency range of the amplifier; and

applying said control value to the amplifier to adjust said bias voltage to tune said amplifier to a desired frequency range.

59. (Original) The method of claim 58, further comprising:

monitoring the amplified signal from the amplifier in the controller to confirm that the amplifier is tuned;

modifying said control value applied to the amplifier from the controller to adjust said bias voltage to tune said amplifier; and

storing said modified control value in the look up table.

60. (Original) The method of claim 53, wherein adjusting a bias voltage further comprises: providing a control value to said controller from said look up table to change a frequency range of said receiver; and

applying said control value to said receiver to tune said receiver to a desired frequency range.

- 61. (Original) The method of claim 53, wherein adjusting a bias voltage further comprises varying a supply voltage applied to said amplifier from said controller to adjust said bias voltage on said parasitic capacitance.
- 62. (Original) The method of claim 53, wherein amplifying said RF signal further comprises amplifying said RF signal in a low noise amplifier (LNA) coupled to said antenna.
- 63. (Original) The method of claim 53, further comprising:
 recording, after adjusting said bias voltage, a parameter value related to said bias voltage
 for an operational frequency range;

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repeating the adjusting and recording operations for a different operational frequency range; and

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generating a table of parameter values corresponding to a plurality of different operational frequency ranges for subsequent use in tuning said amplifier.